

**TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT**  
(Under 37 CFR 1.97(b) or 1.97(c))

In Re Application: **Fwu-Iuan Hshieh et al.**

Serial No. Unassigned	Filing Date Filed Herewith	Examiner Unassigned	Group A Unassigned
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**TRENCH MOSFET DEVICE WITH POLYCRYSTALLINE SILICON SOURCE CONTACT  
STRUCTURE**

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(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

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Karin L. Williams  
Signature

Dated: 11/20/01

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**TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT**  
**(Under 37 CFR 1.97(b) or 1.97(c))**

Docket No.  
GS 150

In Re Application Of: **Fwu-Iuan Hshieh et al.**

Serial No.  
Unassigned

Filing Date  
Filed Herewith

Examiner  
Unassigned

Group Art Unit  
Unassigned

Title: **TRENCH MOSFET DEVICE WITH POLYCRYSTALLINE SILICON SOURCE CONTACT  
STRUCTURE**

Address to:  
**Assistant Commissioner for Patents  
Washington, D.C. 20231**

**37 CFR 1.97(b)**

- ☒ The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.

**37 CFR 1.97(c)**

- ☐ The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:
- ☐ the statement specified in 37 CFR 1.97(e);
- OR**
- ☐ the fee set forth in 37 CFR 1.17(p).